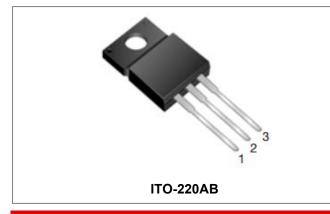


STF10150C(R)

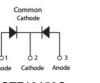
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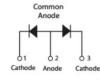


STF10150C(R) SCHOTTKY RECTIFIER



Circuit Diagram





STF10150C

STF10150CR

Features

- 150 °C T_J operation
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Trench MOS Schottky technology
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	150	V
Average Rectified Forward Current	lf (AV)	50% duty cycle @Tc=105°C, rectangular wave form	5(Per Leg) 10(Per Device)	А
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse, Tc=25°C	120	А

Electrical Characteristics:

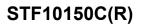
Characteristics	Symbol	Condition	Тур.	Max.	Units	
Forward Voltage Drop(Per Leg)*	V _{F1}	@ 3A, Pulse, T _J = 25 °C	0.80	-	V	
		@ 5A, Pulse, T _J = 25 °C	1.08	1.41		
	V _{F2}	@ 3A, Pulse, T _J = 125 °C	0.60	-	V	
		@ 5A, Pulse, T _J = 125 °C	0.69	0.75	v	
Reverse Current(Per Leg)*	I _{R1}	$@V_R = rated V_{R_j}T_J = 25^{\circ}C$	0.002	0.1	mA	
	I _{R2}	@V _R = rated V _{R,} T _J = 125℃	2	10	mA	
Junction Capacitance(Per Leg)	Ст	@V _R = 5V, T _C = 25 °C, f _{SIG} = 1MHz	200	-	рF	
RSM Isolation Voltage (t = 1.0 second, R. H. < = 30% , T _A = 25 °C)		Clip mounting, the epoxy body away from the heatsink edge by more than 0.110" along the lead direction.	-	4500		
	V _{ISO}	Clip mounting, the epoxy body is inside the heatsink.	-	3500	V	
		Screw mounting, the epoxy body is inside the heatsink.	-	1500		

* Pulse width < 300 μs, duty cycle < 2%

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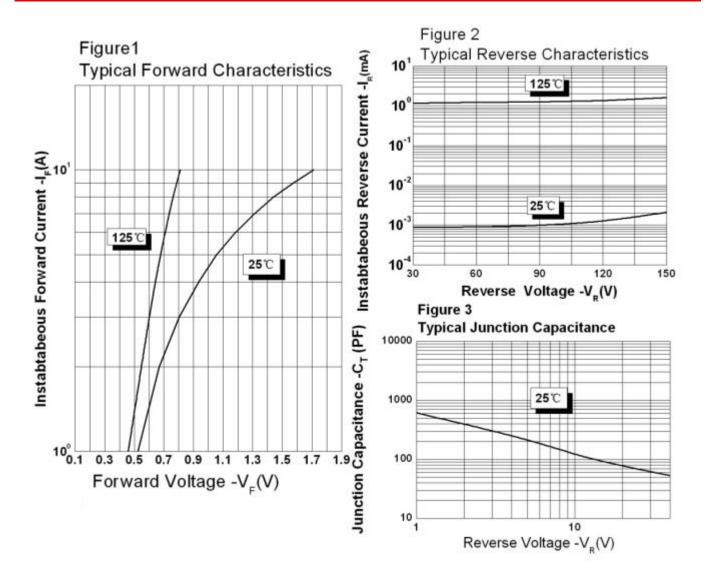


RoHS 😥

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(Per Leg)	$R_{ ext{ heta}JC}$	DC operation	5.5	°C/W
Approximate Weight	wt	-	2	g
Case Style	ITO-220AB			

Ratings and Characteristics Curves



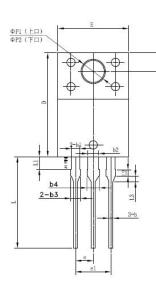


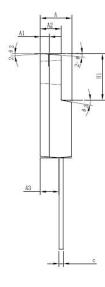
STF10150C(R)



Mechanical Dimensions ITO-220AB

-

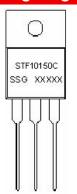




SYMBOL	Millimeters				
STWBOL	MIN.	TYP.	MAX.		
Α	4.30	4.50	4.70		
A1	1.10	1.30	1.50		
A2	2.80	3.00	3.20		
A3	2.50	2.70	2.90		
b	0.50	0.60	0.75		
b1	1.10	1.20	1.35		
b2	1.50	1.60	1.75		
b3	1.20	1.30	1.45		
b4	1.60	1.70	1.85		
С	0.50	0.60	0.75		
D	14.80	15.00	15.20		
E	9.96	10.16	10.36		
е		2.55			
e1		5.10			
H1	6.50	6.70	6.90		
	12.70	13.20	13.70		
L1	1.60	1.80	2.00		
L2	0.80	1.00	1.20		
L3	0.60	0.80	1.00		
ΦP1(上□)	3.30	3.50	3.70		
ΦΡ2 (下口)	2.99	3.19	3.39		
Q	2.50	2.70	2.90		
Θ1		5°			
Θ2		4°			
Θ3		10°			
Θ4		5°			
Θ5		5°			



Marking Diagram

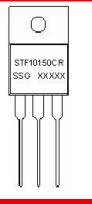


Tube Specification

32mm

7mm

530mm



Where XXXXX is YYWWL

= Device Type ST = Package type F 10 = Forward Current (10A) = Reverse Voltage (150V) 150 C(R) = Configuration SŚĠ = SSG YΥ = Year ww = Week = Lot Number L

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information

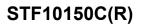
Device	Package	Shipping
STF10150C(R)	ITO-220AB (Pb-Free)	50 pcs/ tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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